

10-639,465

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INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use several sheets if necessary)		APPLICANT YAMAZAKI, et al.	
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U.S. PATENT DOCUMENTS

Examiner Initial	Document Number	Date	Name	Class	Subclass	Filing Date
gag	AA 6,200,866	3-2001	Ma, et al.			
	AB 6,319,840	11-2001	Costrini, et al.			
	AC 6,335,266	1-2002	Kitahara, et al.			
	AD 6,344,383	2-2002	Berry, et al.			
gag	AE 6,348,420	2-2002	Raaijmakers, et al.			
	AF					
	AG					
	AH					
	AI					
	AJ					
	AK					
	AL					

FOREIGN PATENT DOCUMENTS

Examiner Initial	Document Number	Date	Country	Class	Subclass	Translation
gag	AM 11330463	11-1999	Japan			
gag	AN 2805924	9-2001	France			
	AO					
	AP					
	AQ					
	AR					
	AS					
	AT					

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

gag	AU	Polysilicon-Germanium Gate Patterning Studies in a High Density Plasma Helicon Source, 1997 American Vacuum Society, pp. 1874-1880
gag	AV	Germanium Etching in High Density Plasmas for 0.18 PM Complementary Metal-Oxide-Semiconductor Gate Patterning Applications, 1998 American Vacuum Society, pp. 1833-1840
	AW	
	AX	
	AY	
	AZ	
Examiner	George Goudreau	
	Date Considered	3-06'